Effect of pellet size and additive on silica carbothermic reduction in microwave furnace for solar grade silicon

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Silicon as a raw material for solar cells can be produced by numerous methods. The carbothermic reduction of silica using electric arc furnace is the most widely used process in silicon industry. This paper presents a new approach to produce solar grade silicon using microwave furnace. Pellets of different sizes were prepared from a mixture of silica and carbon using water and polyvinyl alcohol as binder agents. Raman spectra indicated a peak at about 515 cm\(^{-1}\) attributed to silicon in the pellets prepared with polyvinyl alcohol, and peaks at about 523 cm\(^{-1}\) and 794 cm\(^{-1}\) attributed to silicon and silicon carbide, in the pellets prepared with water. The pellet size affects the absorption of microwave energy emitted from the magnetrons. Polyvinyl alcohol as a binder agent is promising for the production of silicon using microwave furnace.

Keywords: microwave furnace; carbon; silica; solar grade silicon; solar cells

1. Introduction

For more than 100 years, the process of silicon production has been in continuous development for application in electronic chips and solar panels. Several research projects have been conducted to produce low cost silicon for the photovoltaic industry [1].

Carbothermic reduction is a common industrial procedure to manufacture solar grade silicon from silicon dioxide (SiO\(_2\)) in an electric arc furnace according to the simplified reaction equation:

\[ \text{SiO}_2 + 2\text{C} \rightarrow \text{Si} + 2\text{CO} \] (1)

The reaction in equation 1 seems to be the overall reaction for silicon production. Moreover, many chemical reactions with different stoichiometry are possible in the reaction system between silica and carbon (–) as shown in Table 1.

Nevertheless, the reaction mechanisms are still being researched and developed in order to find new processes, which require the knowledge of how to control this complex reaction system between solid, liquid and gaseous matter, as illustrated in Table 1, and to increase the energy efficiency process during silicon production. Heating a mixture of silica and carbon (mole ratio 1:2) produced silicon carbide (SiC) and silicon monoxide (SiO) but not silicon [2].

Therefore, the reduction of SiO\(_2\) with C, at high temperature, may form silicon monoxide (SiO), carbon monoxide (CO) and silicon carbide (SiC) as shown in Table 1. Where, g, l and s correspond to gas, liquid, and solid phases, respectively. As the reaction in equation 2, equation 3 and equation 5 can be controlled by the amount of silicon monoxide, so it is assumed that SiO is the most important reactant by-product in silicon production. Moreover, the analyses of gas phases using Q-mass spectrometer cannot detect SiO gas but only CO.
Table 1. Possible reactions between SiO$_2$–C during heating process.

<table>
<thead>
<tr>
<th>Reaction equation</th>
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<tbody>
<tr>
<td>$SiO_2 + 2C \rightarrow Si + 2CO$ (1)</td>
</tr>
<tr>
<td>$SiO_2(s) + C(s) \rightarrow SiO(g) + CO(g)$ (2)</td>
</tr>
<tr>
<td>$SiO(g) + 2C(s) \rightarrow SiC(s) + CO(g)$ (3)</td>
</tr>
<tr>
<td>$2SiO_2(s) + SiC(s) \rightarrow 3SiO(g) + CO(g)$ (4)</td>
</tr>
<tr>
<td>$SiO(g) + SiC(s) \rightarrow 2Si(s) + CO(g)$ (5)</td>
</tr>
<tr>
<td>$SiO_2(l) + Si(l) \rightarrow SiO(g)$ (6)</td>
</tr>
</tbody>
</table>

Materials are classified into three different groups when exposed to microwave irradiation: microwave absorbers (silicon carbide, charcoal and activated carbon), microwave transparent (alumina, quartz), and microwave reflectors (solid metals) [6].

The properties of materials and their ability to absorb the power of microwaves depend on how they store the energy, which is connected with a dielectric constant and how they dissipate energy which is connected with dielectric loss. The ratio of these two factors is defined by the loss tangent $\tan \delta$ and the relative permittivity $\varepsilon_r$ according to the following equation:

$$\tan \delta = \frac{\varepsilon''}{\varepsilon'}$$ (7)

In general, frequency dependence of dielectric constant and dielectric loss in some materials is strongly influenced by temperature [8]. Knowing the properties of a material allows us to predict its ability to absorb the energy supplied by magnetrons. The average power absorbed by a certain amount of material when heated dielectrically is expressed as [9]:

$$P = 2\pi f \varepsilon_0 \cdot \varepsilon_r \cdot \tan(\delta) E^2$$ (8)

where is the dissipated power [W/cm$^3$], the energy source is represented by the electrical field strength [V/cm] and is frequency [Hz]; the dielectric constant and the loss tangent are the material properties. Generally, for industrial microwave furnaces, the frequency $f$ is equal to 2.45 GHz [10].

When a microwave radiation penetrates a material, such as a dielectric, an energy loss occurs, because the thermal conductivity of the material depends on the absorption and penetration depth of microwave energy, and then, as thermal conductivity increases, heat dissipation also increases [11]. To determine the uniformity of heating and the depth of the microwaves penetration into a material, it is important to know the dielectric properties of the material [9, 12]. The penetration depth of microwave energy from the surface to the bulk of material is defined as the depth at which the power decreases by half its value [9, 13, 14] In this work,
the results show that the penetration depth is influenced by the pellet size, homogeneity of powder mixture and the additive of polymer.

2. Experimental study

2.1. Heating mechanism

Microwave heating systems in the industrial sector differ from each other depending on their applications. As shown in Fig. 1, the microwave system used in this study includes microwave power supply, magnetron head, cooling system, and waveguide components (isolators/circulators, tuning system and waveguides).

Fig. 1. Schematic illustration of multi-mode microwave heating system.

The sample is heated in a multi-mode microwave furnace by four magnetrons, each having a variable microwave power with a maximum value of 3 kW at a frequency of 2.45 GHz. The tuning system is used to reflect unabsorbed microwaves into the furnace chamber and increase energy efficiency. Moreover, circulators are used to protect the magnetron from reflected microwave energy by a three-port device system using ferrite technology (magnets), typically circulators combined with a water load, which has high power absorption capacity. The temperature is measured by infrared thermometers. The experiments were carried out according to the heating profile after removing all the air from the chamber using a rotary pump to avoid oxygen oxidation and injecting of an inert gas such as argon (Ar).

2.2. Sample

The study aims to investigate the effect of pellet size on the carbothermic reduction of silica sand by microwave irradiation. We have used 3 moles of powdered crystalline silica (SiO₂) (average particle size of 63 µm, Kojundo Chemical Lab. Co., Ltd., Japan) mixed with 2 moles of black carbon (average particle size of 20 µm, Kojundo Chemical Lab. Co., Ltd., Japan), using a mortar and pestle.

Then, we made the pellets with different sizes from the mixed powders and dried them at 80 °C for 90 minutes in a pan. We compared two different binder agents: water and polyvinyl alcohol (PVA) [-CH₂CHOH]-ₙ (Aldrich Chemical Company, USA), as shown in Table 2.

An alumina crucible was used to preserve the prepared pellets, as microwave irradiation does not affect this material which is considered as transparent. The intensity of microwave radiation depends on the design and geometry of the furnace chamber, thus, the crucible must be placed inside the chamber at the point of high concentration of microwave irradiation [15]. Moreover, to avoid energy loss, we used an insulating alumina fiber blanket to cover the crucible. The experiments were carried in an inert atmosphere of Ar gas under a pressure of ∼10⁵ Pa.

During the experiment, an infrared thermometer, with a temperature range of 400 °C to 2500 °C, was used to measure the temperature on the crucible side. Unfortunately, we were unable to use a thermocouple to measure temperature because it causes damages to samples when they are exposed to microwave irradiation [15].

Instead, simulations of the electromagnetic field distribution with the temperature profile can be used to predict the temperature of the mixture inside the crucible during microwave heating of the carbothermic reduction of [16, 17].

3. Results and discussion

The samples after reactions are presented in Fig. 2. Sample a reacted completely at 1496 °C, however, sample b reacted partially (65 %) at 1361 °C. Sample c remained unreacted
Table 2. Raw materials for pellets preparation

<table>
<thead>
<tr>
<th>Sample</th>
<th>Mixture [g]</th>
<th>SiO$_2$–C</th>
<th>Binder agent</th>
<th>Pellets size [mm]</th>
<th>Ratio of binder by weight [%]</th>
</tr>
</thead>
<tbody>
<tr>
<td>(a)</td>
<td>200</td>
<td></td>
<td>water</td>
<td>5</td>
<td>10</td>
</tr>
<tr>
<td>(b)</td>
<td>200</td>
<td></td>
<td>water</td>
<td>7</td>
<td>10</td>
</tr>
<tr>
<td>(c)</td>
<td>200</td>
<td></td>
<td>water</td>
<td>10</td>
<td>10</td>
</tr>
<tr>
<td>(d)</td>
<td>200</td>
<td></td>
<td>PVA</td>
<td>5</td>
<td>3</td>
</tr>
</tbody>
</table>

at a temperature of 1252 °C. The change of the reactions percentages was due to the effect of pellet size and the microwave energy absorption. In sample d, the temperature increased to about 1678 °C. As shown in Fig. 2d, there are many colors: brown, grey metallic and green. The green color corresponds to silicon carbide, brown and metallic grey correspond to different phases of silicon according to the manufacturing conditions [18]. The weight loss of the samples a, b, c and d was 85 g, 35 g, 9 g, and 150 g, respectively. In general, weight loss was caused by the generation of CO, CO$_2$ and SiO gases [3].

3.1. Raman analysis

Raman spectrometer used in our research was (NRS-3300, Jasco, USA). Fig. 3 shows the Raman scattering spectra of sample a, sample b and sample d. In sample a, we notice the presence of peaks at $\sim$523 cm$^{-1}$ which can be attributed to Si, and $\sim$794 cm$^{-1}$ referred to the transverse optical (TO) mode of SiC which consists mainly of a cubic polytype structure [19, 20]. In sample b, the observed peaks correspond to the TO phonon mode at $\sim$789 cm$^{-1}$, and low intensity longitudinal optical (LO) phonon mode at $\sim$973 cm$^{-1}$, attributed to SiC [19, 21].

Moreover, as shown in Fig. 2d, the dominant peak observed is located at $\sim$515 cm$^{-1}$ in position A which corresponds to brown colour silicon, and another peak observed at $\sim$517 cm$^{-1}$ in position B can be attributed to metallic and greyish silicon [22]. These different colors of silicon correspond to the two allotropes of silicon, i.e., crystalline and amorphous silicon.

4. Conclusions

In conclusion, following our experiments we succeeded to produce silicon by a microwave-heating process using a mixture of silica and carbon. It is important to note that many parameters influence the chemical reaction process such as pellet size, binding agent and reaction temperature. Polyvinyl alcohol as a binder agent improved heat transfer and resulted in a 17 % efficiency in silicon production.

On the basis of the promising findings presented in this paper, work on the remaining issues
Fig. 3. Raman scattering spectra of samples a, b and d. (a) peak at 523 cm$^{-1}$ corresponds to silicon and peak at 794 cm$^{-1}$ corresponds to silicon carbide, (b) peaks at 789 cm$^{-1}$ and at 973 cm$^{-1}$ correspond to silicon carbide, (d-A) peak at 517 cm$^{-1}$ corresponds to silicon, (d-B) peak at 517 cm$^{-1}$ corresponds to silicon

is continuing and will be presented in future papers. Therefore, we intend to make a new crucible design to prevent silicon monoxide (SiO) gas loss during the carbothermic reduction, and to achieve continuous production of solar grade silicon under microwave irradiation.

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References

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